

SPHV Series

200W Discrete Unidirectional TVS Diode

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
P_{pk}	Peak Pulse Power ($t_p=8/20\mu s$)	200	W
T_{OP}	Operating Temperature	-40 to 125	°C
T_{STOR}	Storage Temperature	-55 to 150	°C

Caution: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

SPHV12 Electrical Characteristics (TOP=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R \leq 1\mu A$			12.0	V
Breakdown Voltage	V_{BR}	$I_R = 1mA$	13.3			V
Reverse Leakage Current	I_{LEAK}	$V_R = 12V$			1.0	μA
Clamp Voltage ¹	V_C	$I_{PP} = 1A, t_p = 8/20\mu s$, Fwd			19.0	V
		$I_{PP} = 8A, t_p = 8/20\mu s$, Fwd			25.0	V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p = 100ns$, I/O to GND		0.37		Ω
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$			8.0	A
ESD Withstand Voltage ¹	V_{ESD}	IEC61000-4-2 (Contact Discharge)	± 30			kV
		IEC61000-4-2 (Air Discharge)	± 30			kV
Diode Capacitance ¹	$C_{I/O-GND}$	Reverse Bias=0V, f=1MHz			60	pF

Note:

1. Parameter is guaranteed by design and/or device characterization.
2. Transmission Line Pulse (TLP) with 100ns width and 200ps rise time.

SPHV15 Electrical Characteristics (TOP=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R \leq 1\mu A$			15.0	V
Breakdown Voltage	V_{BR}	$I_R = 1mA$	16.7			V
Reverse Leakage Current	I_{LEAK}	$V_R = 15V$			1.0	μA
Clamp Voltage ¹	V_C	$I_{PP} = 1A, t_p = 8/20\mu s$, Fwd			22.0	V
		$I_{PP} = 5A, t_p = 8/20\mu s$, Fwd			28.0	V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p = 100ns$, I/O to GND		0.40		Ω
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$			5.0	A
ESD Withstand Voltage ¹	V_{ESD}	IEC61000-4-2 (Contact Discharge)	± 30			kV
		IEC61000-4-2 (Air Discharge)	± 30			kV
Diode Capacitance ¹	$C_{I/O-GND}$	Reverse Bias=0V, f=1MHz			46	pF

Note:

1. Parameter is guaranteed by design and/or device characterization.
2. Transmission Line Pulse (TLP) with 100ns width and 200ps rise time.

SPHV Series

200W Discrete Unidirectional TVS Diode

SPHV24 Electrical Characteristics (TOP=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R \leq 1 \mu A$			24.0	V
Breakdown Voltage	V_{BR}	$I_R = 1 mA$	26.7			V
Reverse Leakage Current	I_{LEAK}	$V_R = 24V$			1.0	μA
Clamp Voltage ¹	V_C	$I_{PP} = 1A, t_p = 8/20\mu s, Fwd$			36.0	V
		$I_{PP} = 3A, t_p = 8/20\mu s, Fwd$			50.0	V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p = 100ns$, I/O to GND		0.56		Ω
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$			3.0	A
ESD Withstand Voltage ¹	V_{ESD}	IEC61000-4-2 (Contact Discharge)	± 24			kV
		IEC61000-4-2 (Air Discharge)	± 30			kV
Diode Capacitance ¹	$C_{I/O-GND}$	Reverse Bias=0V, f=1MHz			32	pF

Note:

1. Parameter is guaranteed by design and/or device characterization.
 2. Transmission Line Pulse (TLP) with 100ns width and 200ps rise time.

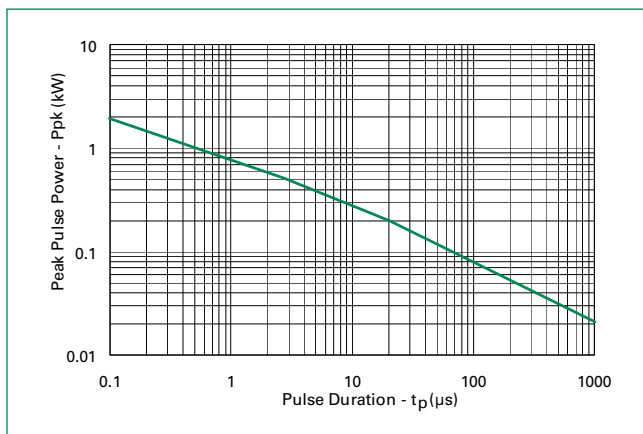
SPHV36 Electrical Characteristics (TOP=25°C)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Reverse Standoff Voltage	V_{RWM}	$I_R \leq 1 \mu A$			36.0	V
Breakdown Voltage	V_{BR}	$I_R = 1 mA$	40.0			V
Reverse Leakage Current	I_{LEAK}	$V_R = 36V$			1.0	μA
Clamp Voltage ¹	V_C	$I_{PP} = 1A, t_p = 8/20\mu s, Fwd$			52.0	V
		$I_{PP} = 2A, t_p = 8/20\mu s, Fwd$			60.0	V
Dynamic Resistance ²	R_{DYN}	TLP, $t_p = 100ns$, I/O to GND		1.28		Ω
Peak Pulse Current	I_{PP}	$t_p = 8/20\mu s$			2.0	A
ESD Withstand Voltage ¹	V_{ESD}	IEC61000-4-2 (Contact Discharge)	± 15			kV
		IEC61000-4-2 (Air Discharge)	± 20			kV
Diode Capacitance ¹	$C_{I/O-GND}$	Reverse Bias=0V, f=1MHz			25	pF

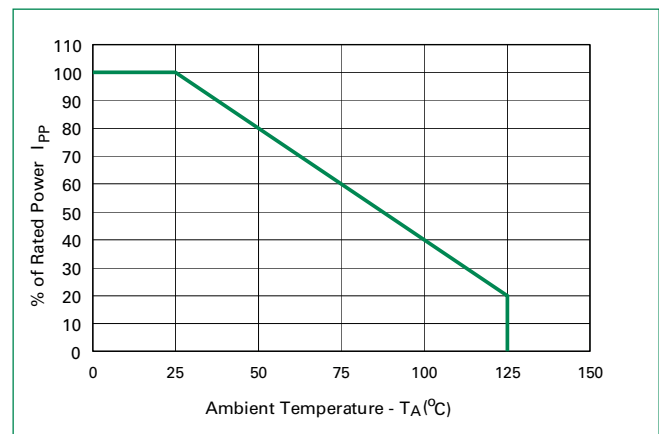
Note:

1. Parameter is guaranteed by design and/or device characterization.
 2. Transmission Line Pulse (TLP) with 100ns width and 200ps rise time.

Non-Repetitive Peak Pulse Power vs. Pulse Time

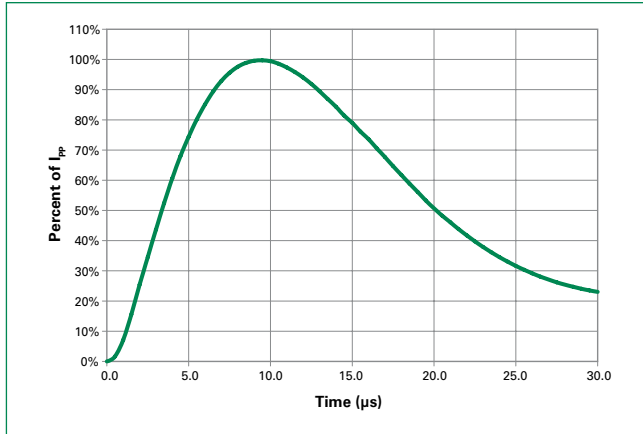


Power Derating Curve

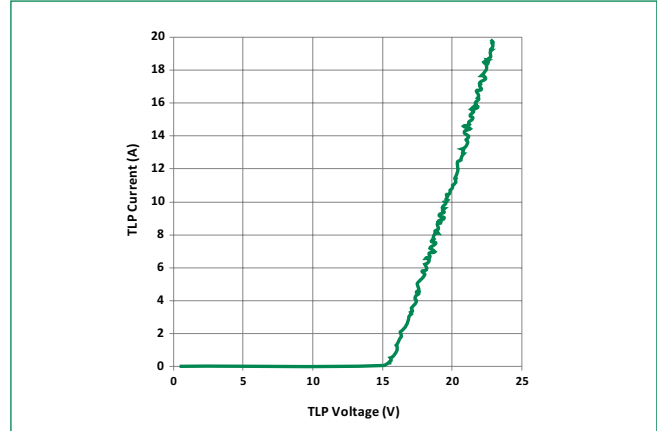


SPHV Series

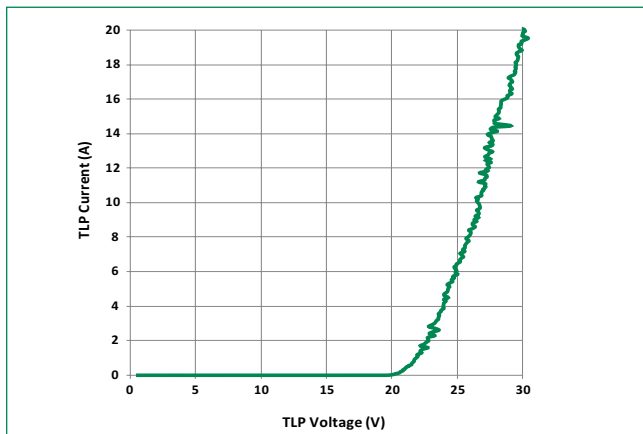
200W Discrete Unidirectional TVS Diode

8/20 μ s Pulse Waveform

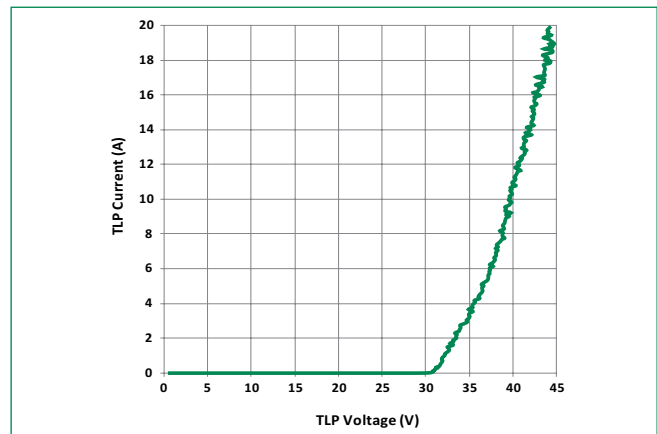
SPHV12 Transmission Line Pulsing(TLP) Plot



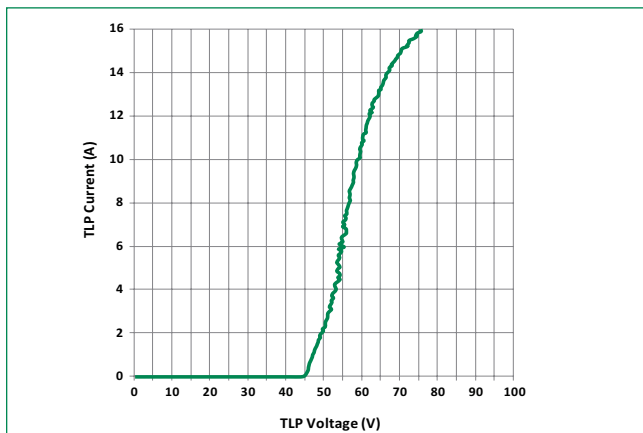
SPHV15 Transmission Line Pulsing(TLP) Plot



SPHV24 Transmission Line Pulsing(TLP) Plot



SPHV36 Transmission Line Pulsing(TLP) Plot

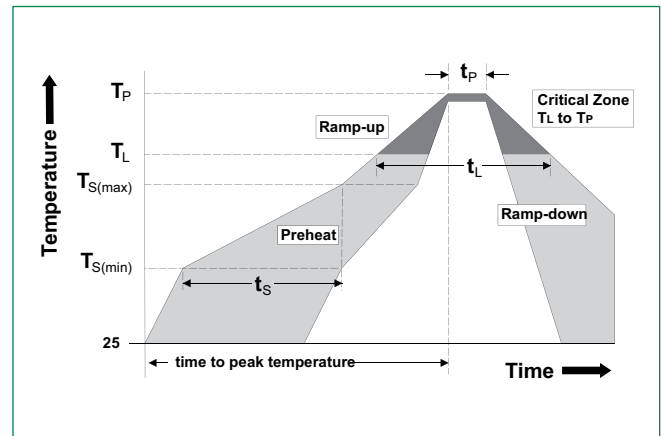


SPHV Series

200W Discrete Unidirectional TVS Diode

Soldering Parameters

Reflow Condition		Pb – Free assembly
Pre Heat	-Temperature Min ($T_{s(min)}$)	150°C
	-Temperature Max ($T_{s(max)}$)	200°C
	-Time (min to max) (t_s)	60 – 180 secs
Average ramp up rate (Liquidus) Temp (T_L) to peak		3°C/second max
$T_{s(max)}$ to T_L - Ramp-up Rate		3°C/second max
Reflow	-Temperature (T_L) (Liquidus)	217°C
	-Temperature (t_L)	60 – 150 seconds
Peak Temperature (T_p)		260 ^{+0/-5} °C
Time within 5°C of actual peak Temperature (t_p)		20 – 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T_p)		8 minutes Max.
Do not exceed		260°C



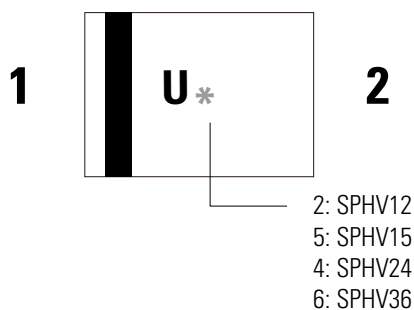
Product Characteristics

Lead Plating	Matte Tin, Pre-Plated Frame
Lead Material	Copper Alloy
Substitute Material	Silicon
Body Material	Molded Compound
Flammability	UL Recognized compound meeting flammability rating V-0

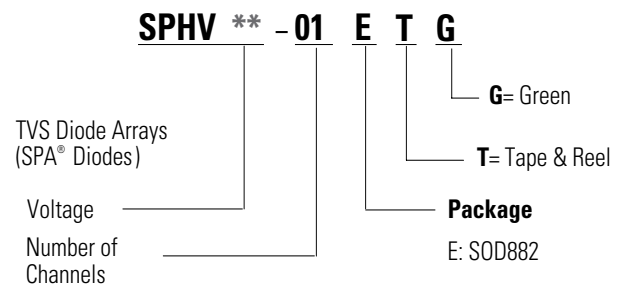
Ordering Information

Part Number	Package	Marking	Min. Order Qty.
SPHV12-01ETG	SOD882	U2	10000
SPHV15-01ETG		U5	
SPHV24-01ETG		U4	
SPHV36-01ETG		U6	

Part Marking System



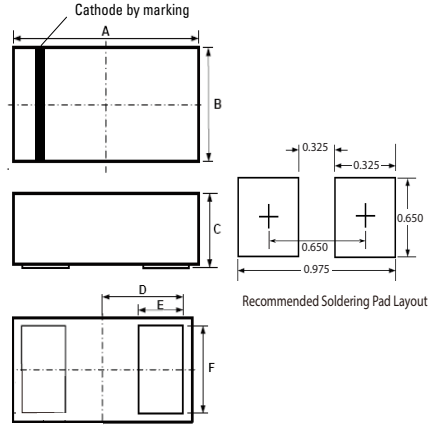
Part Numbering System



SPHV Series

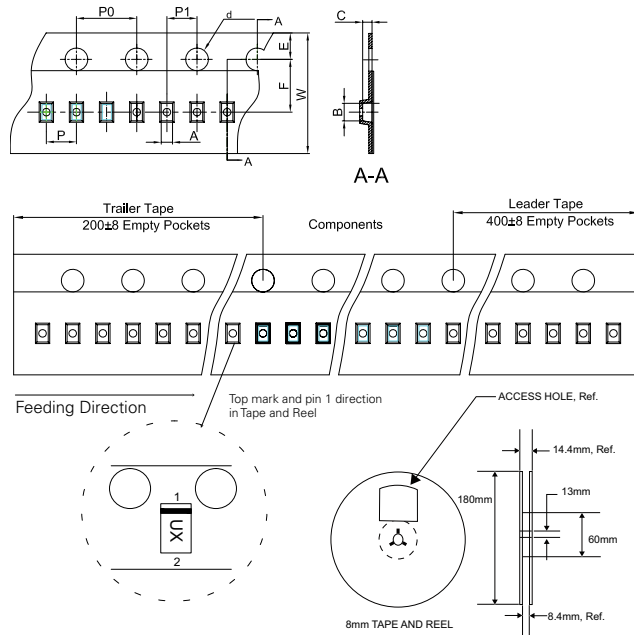
200W Discrete Unidirectional TVS Diode

Package Dimensions — SOD882(SPHVxx-01ETG)



Symbol	Package JEDEC	SOD882					
		MO-236					
		Millimeters			Inches		
		Min	Typ	Max	Min	Typ	Max
A		0.90	1.00	1.10	0.037	0.039	0.041
B		0.50	0.60	0.70	0.022	0.024	0.026
C		0.40	0.50	0.60	0.016	0.020	0.024
D			0.45			0.018	
E		0.20	0.25	0.35	0.008	0.010	0.012
F		0.45	0.50	0.55	0.018	0.020	0.022

Embossed Carrier Tape & Reel Specification



Symbol	Millimeters
A	0.70+/-0.045
B	1.10+/-0.045
C	0.65+/-0.045
d	1.55+/-0.10
E	1.75+/-0.05
F	3.50+/-0.05
P	2.00+/-0.10
P0	4.00+/-0.10
P1	2.00+/-0.10
W	8.00 + 0.30 -0.10

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